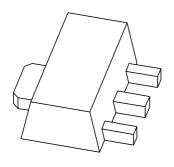
DISCRETE SEMICONDUCTORS

DATA SHEET



BST60; BST61; BST62 PNP Darlington transistors

Product specification Supersedes data of 2001 Feb 20

2004 Dec 09





PNP Darlington transistors

BST60; **BST61**; **BST62**

FEATURES

- High current (max. 0.5 A)
- Low voltage (max. 80 V)
- Integrated diode and resistor.

APPLICATIONS

- Industrial switching applications such as:
 - Print hammer
 - Solenoid
 - Relay and lamp driving.

DESCRIPTION

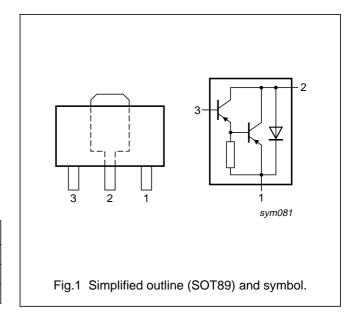
PNP Darlington transistor in a SOT89 plastic package. NPN complements: BST50, BST51 and BST52.

MARKING

TYPE NUMBER	MARKING CODE
BST60	BS1
BST61	BS2
BST62	BS3

PINNING

PIN	DESCRIPTION	
1	emitter	
2	collector	
3	base	



ORDERING INFORMATION

TYPE NUMBER	PACKAGE			
I TPE NUMBER	NAME	DESCRIPTION	VERSION	
BST60	SC-62	plastic surface mounted package; collector pad for good heat	SOT89	
BST61		transfer; 3 leads		
BST62				

PNP Darlington transistors

BST60; BST61; BST62

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter			
	BST60		_	-60	V
	BST61		_	-80	V
	BST62		_	-90	V
V _{CES}	collector-emitter voltage	V _{BE} = 0 V			
	BST60		_	-45	V
	BST61		_	-60	V
	BST62		_	-80	V
V _{EBO}	emitter-base voltage	open collector	_	-5	V
I _C	collector current (DC)		_	-1	Α
I _{CM}	peak collector current		_	-2	Α
I _B	base current (DC)		_	-100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	_	1.3	W
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T _{amb}	ambient temperature		-65	+150	°C

Note

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	note 1	96	K/W
R _{th(j-s)}	thermal resistance from junction to soldering point		16	K/W

Note

Device mounted on a printed-circuit board, single-sided copper, tin-plated, mounting pad for collector 6 cm².
 For other mounting conditions, see "Thermal considerations for SOT89 in the General Part of associated Handbook".

^{1.} Device mounted on a printed-circuit board, single-sided copper, tin-plated, mounting pad for collector 6 cm². For other mounting conditions, see "Thermal considerations for SOT89 in the General Part of associated Handbook".

PNP Darlington transistors

BST60; BST61; BST62

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

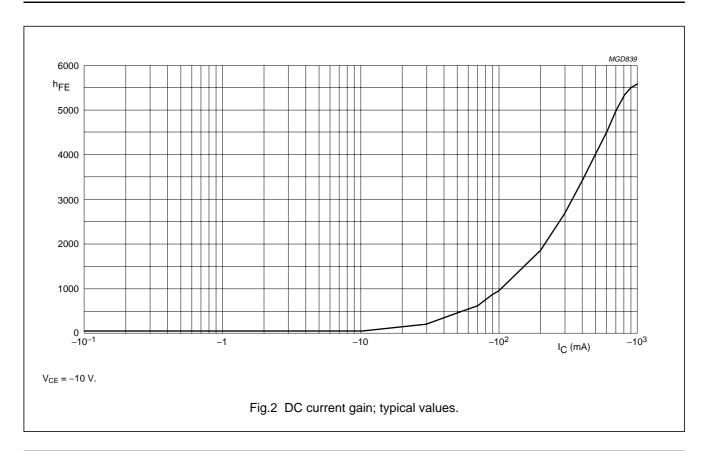
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CES}	collector-emitter cut-off current					
	BST60	$V_{BE} = 0 \text{ V}; V_{CE} = -45 \text{ V}$	_	-	-50	nA
	BST61	$V_{BE} = 0 \text{ V}; V_{CE} = -60 \text{ V}$	_	_	-50	nA
	BST62	$V_{BE} = 0 \text{ V}; V_{CE} = -80 \text{ V}$	_	-	-50	nA
I _{EBO}	emitter-base cut-off current	$I_C = 0 \text{ A}; V_{EB} = -4 \text{ V}$	_	_	-50	nA
h _{FE}	DC current gain	V _{CE} = −10 V; note 1; see Fig.2				
		I _C = −150 mA	1000	-	_	
		$I_{C} = -500 \text{ mA}$	2000	-	_	
V _{CEsat}	collector-emitter saturation	$I_C = -500 \text{ mA}; I_B = -0.5 \text{ mA}$	_	_	-1.3	V
	voltage	$I_C = -500 \text{ mA}; I_B = -0.5 \text{ mA};$ $T_j = 150 \text{ °C}$	_	-	-1.3	V
V _{BEsat}	base-emitter saturation voltage	$I_C = -500 \text{ mA}; I_B = -0.5 \text{ mA}$	_	_	-1.9	V
f _T	transition frequency	$I_C = -500 \text{ mA}; V_{CE} = -5 \text{ V};$ f = 100 MHz	_	200	_	MHz
Switching ti	Switching times (between 10% and 90% levels); (see Fig.3)					
t _{on}	turn-on time	$I_{Con} = -500 \text{ mA}; I_{Bon} = -0.5 \text{ mA};$	_	500	_	ns
t _{off}	turn-off time	I _{Boff} = 0.5 mA	_	700	_	ns

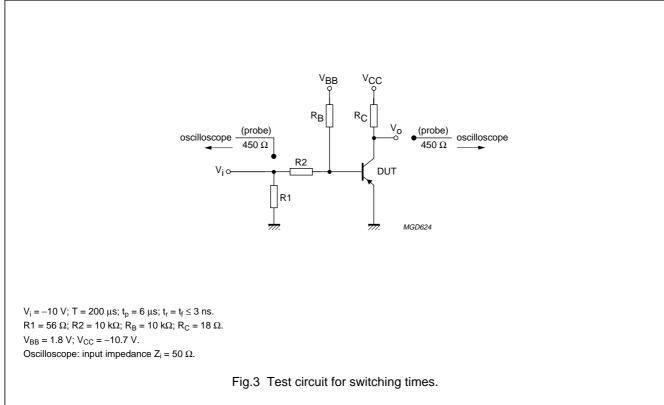
Note

1. Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$

PNP Darlington transistors

BST60; BST61; BST62





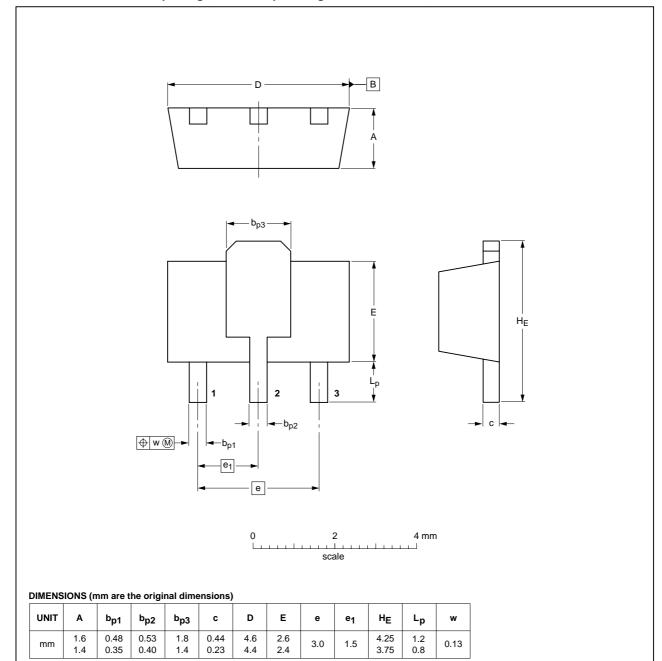
PNP Darlington transistors

BST60; BST61; BST62

PACKAGE OUTLINE

Plastic surface mounted package; collector pad for good heat transfer; 3 leads

SOT89



OUTLINE	REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT89		TO-243	SC-62			99-09-13 04-08-03

PNP Darlington transistors

BST60; BST61; BST62

DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS(2)(3)	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

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